# Single Non-Inverting Buffer with Open Drain Output

The NL17SZ07 is a high performance single non-inverting buffer with open drain outputs operating from a 1.65 to 5.5 V supply.

The Output stage is open drain with Over Voltage Tolerance. This allows the NL17SZ07 to be used to interface 5.0 V circuits to circuits of any voltage between 0 and +7.0 V.

#### **Features**

- Tiny SOT-353, SOT-553 and SOT-953 Packages
- Extremely High Speed:  $t_{PD}$  2.5 ns (typical) at  $V_{CC} = 5 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation, CMOS Compatible
- • Over Voltage Tolerant Inputs  $V_{IN}$  may be Between 0 and 7.0 V for  $V_{CC}$  Between 0.5 and 5.5 V
- TTL Compatible Interface Capability with 5.0 V TTL Logic with  $V_{CC}$  = 2.7 V to 3.6 V
- LVCMOS Compatible
- 24 mA Output Sink Capability, Pullup may be between 0 and 7.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 20
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

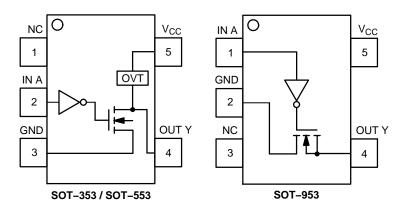


Figure 1. Pinout



Figure 2. Logic Symbol



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#### MARKING DIAGRAMS



SC-88A / SOT-353 / SC-70 DF SUFFIX CASE 419A





SOT-553 XV5 SUFFIX CASE 463B



L7 = Device Code

M = Date Code\*

■ Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.





S = Specific Device Code M = Month Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

## **PIN ASSIGNMENT** (SOT-353 / SOT-553)

Pin	Function
1	NC
2	IN A
3	GND
4	OUT Y
5	V <sub>CC</sub>

# PIN ASSIGNMENT (SOT-953)

Pin	Function	
1	IN A	
2	GND	
3	NC	
4	OUT Y	
5	V <sub>CC</sub>	

### **FUNCTION TABLE**

Input	Output
A	Y
L	L
Н	Z

### **MAXIMUM RATINGS**

Symbol	CI	haracteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \le V_1 \le +7.0$	V
Vo	DC Output Voltage (SOT-953 Pa	ackage) (Note 1)	-0.5 to V <sub>CC</sub> + 0.5	V
	DC Output Voltage (SOT-353 / SOT-553 Packages)	Active Mode, LOW State (Note 1) Tri–State Mode Power–Down Mode ( $V_{CC} = 0 V$ )	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +7.0 -0.5 to +7.0	
I <sub>OK</sub>	$ \begin{array}{lll} DC \ Output \ Diode \ Current \\ (SOT-953 \ Package) & V_O < GND, \ V_O > V_{CC} \\ (SOT-353 \ / \ SOT-553 \ Packages) & V_O < GND \end{array} $		±50 -50	mA
I <sub>IK</sub>	DC Input Diode Current	-50	mA	
Io	DC Output Sink Current	±50	mA	
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA	
I <sub>GND</sub>	DC Ground Current per Ground F	±100	mA	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
P <sub>D</sub>	Power Dissipation in Still Air	SOT-353 SOT-553	186 135	mW
$\theta_{JA}$	Thermal Resistance	SOT-353 SOT-553	350 496	°C/W
T <sub>L</sub>	Lead Temperature, 1 mm from Ca	ase for 10 Seconds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
I <sub>Latch-Up</sub>	Latch-Up Performance	Above V <sub>CC</sub> and Below GND at 85°C (Note 5)	±100	mA
MSL	Moisture Sensitivity	Level 1		
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	2000 200 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Io absolute maximum rating must be observed.

2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.

3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.

- 4. Tested to JESD22-C101-A.
- Tested to EIA/JESD78.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Param	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage (SOT-953 Package)		0	V <sub>CC</sub>	V
	Output Voltage (SOT-353 / SOT-553 Packages)	Active Mode, LOW State Tri–State Mode Power–Down Mode ( $V_{CC} = 0 V$ )	0 0 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Free–Air Temperature		<b>-</b> 55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS

			V	Т	<sub>A</sub> = 25°	С	–55°C ≤T,	<u> </u>	
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>LKG</sub>	Z–State Output Leakage Current	$V_{IN} = V_{IH}$ $V_{OUT} = V_{CC}$ or GND	2.3 to 5.5			±5.0		±10.0	μΑ
V <sub>OL</sub>	Low-Level Output	I <sub>OL</sub> = 100 μA	1.65 to 5.5		0.0	0.1		0.1	V
	Voltage V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 4 mA	1.65		0.08	0.24		0.24	
	"' "-	$I_{OL} = 8 \text{ mA}$	2.3		0.20	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 32 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current (SOT-353/ SOT-553 Packages)	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1		10	μΑ
Icc	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1		10	μΑ
I <sub>CCT</sub>	Quiescent Supply Current	V <sub>IN</sub> = 3.0 V	3.6			10		100	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS  $t_R$  =  $t_F$  = 2.5 ns;  $C_L$  = 50 pF;  $R_L$  = 500  $\Omega$ 

				Т	A = 25°	<b>:</b>	–55°C ≤T,	<sub>4</sub> ≤ 125°C	
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay	$R_{L} = R_1 = 500 \Omega, C_L = 50 pF$	1.8 ± 0.15	0.8	5.3	11.6	0.8	12.0	ns
(Figure 3 and 4)			2.5 ± 0.2	1.2	3.7	5.8	1.2	6.4	
			3.3 ± 0.3	0.8	2.9	4.4	0.8	4.8	
			5.0 ± 0.5	0.5	2.3	3.5	0.5	3.9	
t <sub>PLZ</sub>	Propagation Delay	$R_{L=} R_{1} = 500 \Omega, C_{L} = 50 pF$	1.8 ± 0.15	0.8	5.3	11.6	0.8	1.20	ns
	(Figure 3 and 4)		2.5 ± 0.2	1.2	2.8	5.8	1.2	6.4	
			3.3 ± 0.3	0.8	2.1	4.4	0.8	4.8	
			5.0 ± 0.5	0.5	1.4	3.5	0.5	3.9	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_{I} = 0 \text{ V or } V_{CC}$	>2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	4.0	pF

<sup>6.</sup>  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

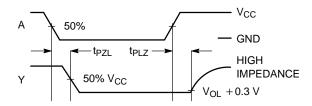
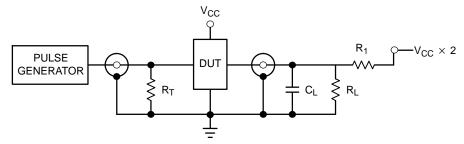


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

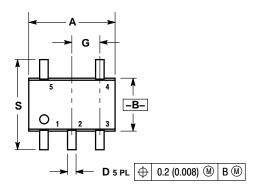
# **DEVICE ORDERING INFORMATION**

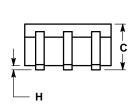
Device	Package	Shipping <sup>†</sup>	
NL17SZ07DFT2G	SOT-353/SC70-5/SC-88A (Pb-Free)	3000 / Tape & Reel	
NL17SZ07XV5T2G	SOT-553 (Pb-Free)	4000 / Tape & Reel	
NL17SZ07P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel	

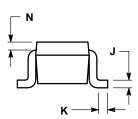
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **PACKAGE DIMENSIONS**

# SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE L



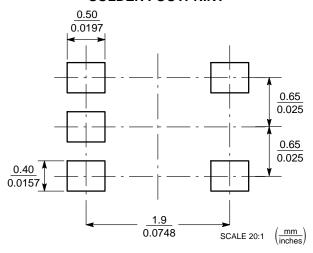




- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2 00	2 20

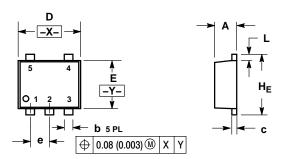
### **SOLDER FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **PACKAGE DIMENSIONS**

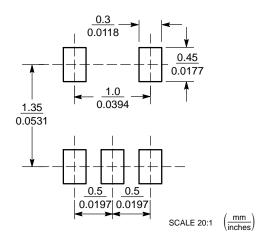
SOT-553 **XV5 SUFFIX** CASE 463B ISSUE C



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.

	MILLIMETERS			MILLIMETERS INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
е		0.50 BSC		0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

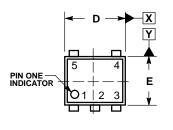
#### **SOLDERING FOOTPRINT\***



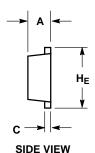
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

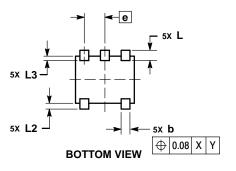
#### PACKAGE DIMENSIONS

#### SOT-953 CASE 527AE ISSUE E



**TOP VIEW** 



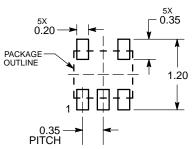


#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS
  MAXIMUM LEAD THICKNESS INCLUDES LEAD
  FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS, OR GATE BURRS.

	MIL	MILLIMETERS					
DIM	MIN	NOM	MAX				
Α	0.34	0.37	0.40				
b	0.10	0.15	0.20				
С	0.07	0.12	0.17				
D	0.95	1.00	1.05				
E	0.75	0.80	0.85				
е		0.35 BS	С				
HE	0.95	1.00	1.05				
L		0.175 REF					
L2	0.05	0.10	0.15				
L3			0.15				

#### **SOLDERING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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